

# **General Description**

The WST3401 is the highest performance trench P-Ch MOSFET with extreme high cell density , which provide excellent RDSON and gate charge for most of the small power switching and load switch applications .

The WST3401 meet the RoHS and Green Product requirement , with full function reliability approved.

#### **Features**

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

#### **Product Summery**

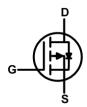
BVDSS	RDSON	ID
-30V	44mΩ	-5.5A

#### **Applications**

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

# **SOT-23-3L Pin Configuration**





# **Absolute Maximum Ratings**

		Rating		
Symbol	Parameter	10s Steady State		Units
$V_{DS}$	Drain-Source Voltage	-30		V
$V_{GS}$	Gate-Source Voltage	±12		V
I <sub>D</sub> @T <sub>C</sub> =25℃	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup>	-6.0	-5.5	Α
I <sub>D</sub> @T <sub>C</sub> =70°C	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup>	-4.9	-4.3	Α
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup>	-17		Α
P <sub>D</sub> @T <sub>A</sub> =25℃	Total Power Dissipation <sup>3</sup>	1.32	1	W
P <sub>D</sub> @T <sub>A</sub> =70°C	Total Power Dissipation <sup>3</sup>	0.84	0.64	W
T <sub>STG</sub>	Storage Temperature Range	-55 to 150		$^{\circ}$
$T_J$	Operating Junction Temperature Range	-55 t	-55 to 150	

# **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit
$R_{ heta JA}$	Thermal Resistance Junction-Ambient <sup>1</sup>		125	°C/W
$R_{ heta JA}$	Thermal Resistance Junction-Ambient <sup>1</sup> (t ≤10s)		95	°C/W
$R_{ heta JC}$	Thermal Resistance Junction-Case <sup>1</sup>		80	°C/W



# Electrical Characteristics (T<sub>J</sub>=25 ℃ unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS}$ =0V , $I_D$ =-250uA	-30			V
$\triangle BV_{DSS}/\triangle T_{J}$	BV <sub>DSS</sub> Temperature Coefficient	Reference to 25 $^{\circ}\!$		-0.023		V/°C
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =-10V , I <sub>D</sub> =-3A		44	52	mΩ
		$V_{GS}$ =-4.5V , $I_D$ =-2A		50	58	
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>GS</sub> =V <sub>DS</sub> . I <sub>D</sub> =-250uA	-0.6		-1.2	V
$\triangle V_{GS(th)}$	V <sub>GS(th)</sub> Temperature Coefficient	— V <sub>GS</sub> −V <sub>DS</sub> , I <sub>D</sub> −-250uA		4		mV/℃
	Drain Source Leakage Current	$V_{DS}\text{=-}24V$ , $V_{GS}\text{=}0V$ , $T_J\text{=}25^{\circ}\text{C}$	<sub>GS</sub> =0V , T <sub>J</sub> =25℃	-1		
I <sub>DSS</sub>	Drain-Source Leakage Current	$V_{DS}$ =-24V , $V_{GS}$ =0V , $T_J$ =55 $^{\circ}$ C			-5	· uA
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm$ 12 $V$ , $V_{DS}$ =0 $V$			±100	nA
gfs	Forward Transconductance	$V_{DS}$ =-5 $V$ , $I_D$ =-3 $A$		11		S
$Q_g$	Total Gate Charge (-4.5V)	V <sub>DS</sub> =-15V , V <sub>GS</sub> =-4.5V , I <sub>D</sub> =-3A		6.4	9.0	
$Q_gs$	Gate-Source Charge			2.3	3.2	nC
$Q_gd$	Gate-Drain Charge			1.9	2.7	
T <sub>d(on)</sub>	Turn-On Delay Time			2.8	5.6	
Tr	Rise Time	$V_{DD}$ =-15 $V$ , $V_{GS}$ =-10 $V$ , $R_{G}$ =3.3 $\Omega$ ,		8.4	15.1	no
$T_{d(off)}$	Turn-Off Delay Time	I <sub>D</sub> =-3A		39	78.0	ns
T <sub>f</sub>	Fall Time			6	12.0	
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =-15V , V <sub>GS</sub> =0V , f=1MHz		583	816	
Coss	Output Capacitance			100	140	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			80	112	

#### **Diode Characteristics**

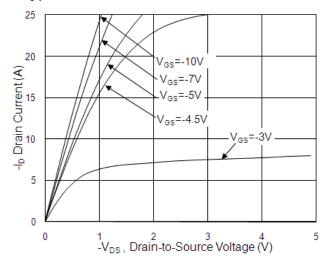
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current <sup>1,4</sup>	V =V =0V Force Current			-4.3	Α
I <sub>SM</sub>	Pulsed Source Current <sup>2,4</sup>	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current			-17	Α
$V_{SD}$	Diode Forward Voltage <sup>2</sup>	$V_{GS}$ =0V , $I_{S}$ =-1A , $T_{J}$ =25 $^{\circ}$ C			-1	V
t <sub>rr</sub>	Reverse Recovery Time			7.8		nS
Q <sub>rr</sub>	Reverse Recovery Charge	IF=-3A,dI/dt=100A/µs,T <sub>J</sub> =25℃		2.5		nC

#### Note

- $1. The \ data \ tested \ by \ surface \ mounted \ on \ a \ 1 \ inch^2 FR-4 \ board \ with \ 2OZ \ copper, t<10 sec.$
- 2.The data tested by pulsed , pulse width  $\,\leq\,300\text{us}$  , duty cycle  $\,\leq\,2\%$
- 4. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.



# **Typical Characteristics**



**Fig.1 Typical Output Characteristics** 

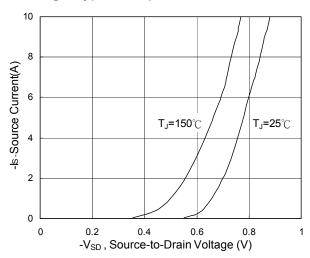


Fig.3 Forward Characteristics of Reverse

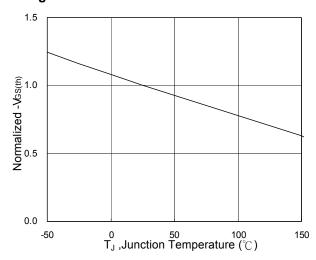


Fig.5 Normalized  $V_{GS(th)}$  vs.  $T_J$ 

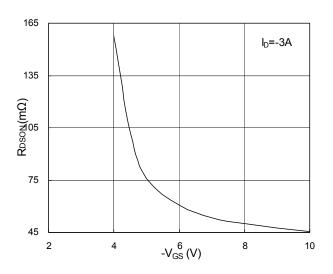


Fig.2 On-Resistance v.s Gate-Source

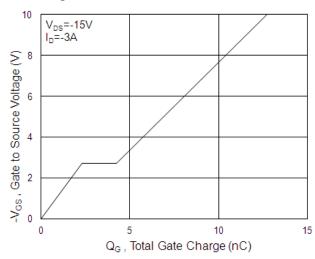


Fig.4 Gate-Charge Characteristics

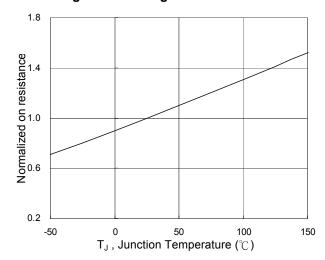
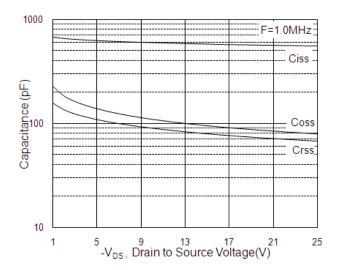


Fig.6 Normalized R<sub>DSON</sub> vs T<sub>J</sub>





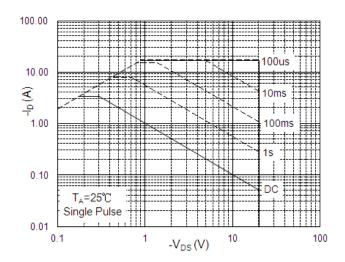


Fig.7 Capacitance

Fig.8 Safe Operating Area

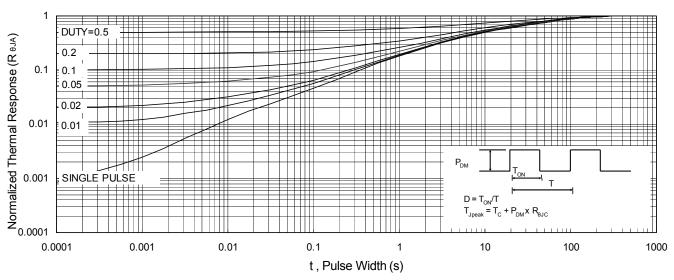
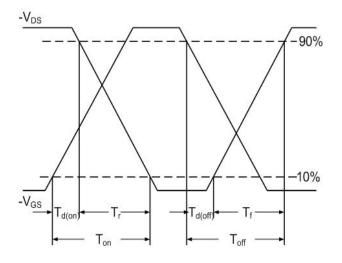


Fig.9 Normalized Maximum Transient Thermal Impedance



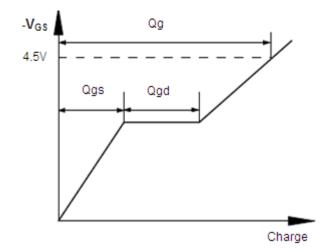


Fig.10 Switching Time Waveform

Fig.11 Gate Charge Waveform



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